

FMMT634Q

## 100V NPN DARLINGTON TRANSISTOR IN SOT23

## **Description**

This Bipolar Junction Transistor (BJT) has been designed to meet the stringent requirements of Automotive Applications.

#### **Features**

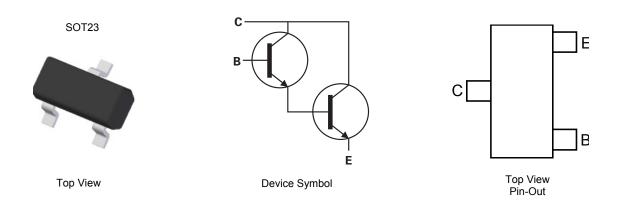
- BV<sub>CEO</sub> > 100V
- I<sub>C</sub> = 900mA high Continuous Collector Current
- I<sub>CM</sub> = 5A Peak Pulse Current
- 625mW Power dissipation
- h<sub>FE</sub> > 5k up to 2A for high current gain hold up
- Complementary PNP Type: FMMT734Q
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight 0.008 grams (approximate)

## **Applications**

- Automotive
- Lamp
- Relay
- Solenoid Driving



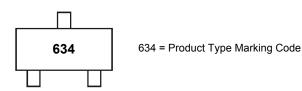
## Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT634QTA	Automotive	634	7	8	3 000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html

## **Marking Information**







FMMT634Q

# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	120	V
Collector-Emitter Voltage	V <sub>CEO</sub>	100	V
Emitter-Base Voltage	$V_{EBO}$	12	V
Continuous Collector Current	Ic	900	mA
Peak Pulse Current	I <sub>CM</sub>	5	Α

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P <sub>D</sub>	625	mW
Power Dissipation (Note 7)	P <sub>D</sub>	806	mW
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>θJA</sub>	200	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R <sub>θJA</sub>	155	°C/W
Thermal Resistance, Junction to Leads (Note 8)	R <sub>θJL</sub>	194	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## ESD Ratings (Note 9)

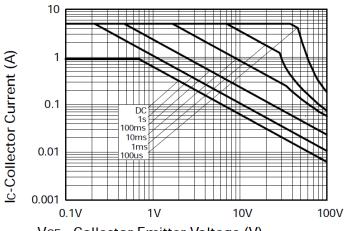
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	2,000	V	2
Electrostatic Discharge - Machine Model	ESD MM	200	V	В

Notes:

- 6. For a device mounted with the exposed collector pad on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Same as note (6), except the device is measured at  $t \le 5$  sec.
- 8. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

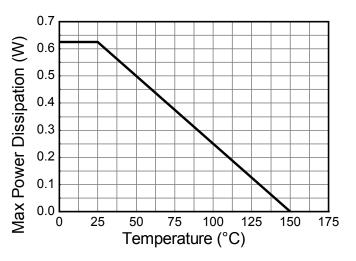


# **Thermal Characteristics and Derating information**

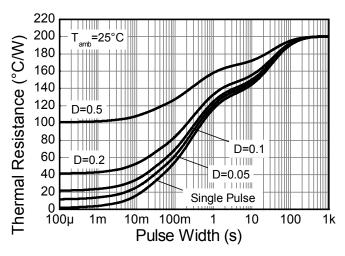


VCE - Collector Emitter Voltage (V)

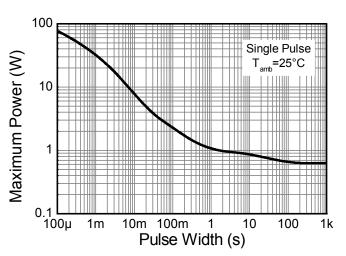
Safe Operating Area



**Derating Curve** 

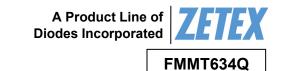


**Transient Thermal Impedance** 



**Pulse Power Dissipation** 



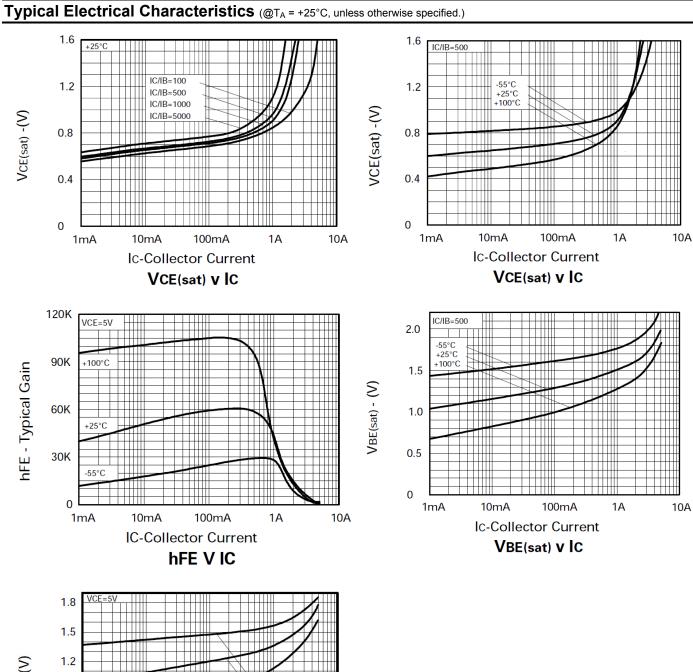


# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	120	170	-	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CEO</sub>	100	115	-	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	12	16	-	V	I <sub>E</sub> = 100μA
Collector Cut-off Current	I <sub>CBO</sub>	-	<1	10	nA	V <sub>CB</sub> = 80V
Emitter Cut-off Current	I <sub>EBO</sub>	-	<1	10	nA	V <sub>EB</sub> = 7V
Collector Emitter Cut-off Current	I <sub>CES</sub>	-	<1	100	nA	V <sub>CES</sub> = 80V
Static Forward Current Transfer Ratio (Note 10)  Collector-Emitter Saturation Voltage (Note 10)	h <sub>FE</sub>	- 20k 15k 5k - - -	50k 60k 40k 14k 24k 600 0.67 0.72	- - - - - - - 0.75 0.80 0.85	- V	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 5V I <sub>C</sub> = 100mA, V <sub>CE</sub> = 5V I <sub>C</sub> = 1A, V <sub>CE</sub> = 5V I <sub>C</sub> = 2A, V <sub>CE</sub> = 5V I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V I <sub>C</sub> = 5A, V <sub>CE</sub> = 5V I <sub>C</sub> = 100mA, I <sub>B</sub> = 1mA I <sub>C</sub> = 250mA, I <sub>B</sub> = 5mA
	32(00.)	- - -	0.82 0.68 0.85	0.93 - 0.96		I <sub>C</sub> = 900mA, I <sub>B</sub> = 5mA I <sub>C</sub> = 900mA, I <sub>B</sub> = 5mA, T <sub>J</sub> = +150°C I <sub>C</sub> = 1A, I <sub>B</sub> = 5mA
Base-Emitter Saturation Voltage (Note 10)	V <sub>BE(sat)</sub>	-	1.5	1.65	V	$I_C = 1A$ , $I_B = 5mA$
Base-Emitter Turn-On Voltage (Note 10)	V <sub>BE(on)</sub>	-	1.33	1.50	V	I <sub>C</sub> = 1A, V <sub>CE</sub> = 5V
Transition Frequency	f <sub>T</sub>	-	140	-	MHz	$I_C = 50$ mA, $V_{CE} = 10$ V, $f = 100$ MHz
Output Capacitance	$C_{obo}$	-	9	20	рF	V <sub>CB</sub> = 10V, f = 1MHz
Turn-On Time	t <sub>(on)</sub>	-	290	-	ns	V <sub>CC</sub> = 20V, I <sub>C</sub> = 500mA,
Turn-Off Time	$t_{(off)}$	-	2,400	-	ns	$I_{B1} = -I_{B2} = 1 \text{mA}$

Note: 10. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%

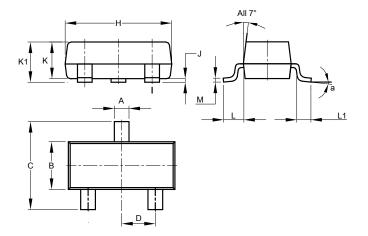






# **Package Outline Dimensions**

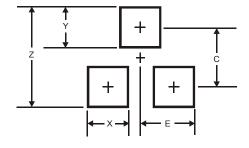
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
7	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L 0.45 0.61 0.5					
L1	0.25	0.55	0.40		
М	<b>M</b> 0.085 0.150 0.1				
а	a 8°				
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

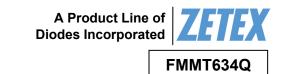


Dimensions	Value (in mm)		
Z	2.9		
X	0.8		
Y	0.9		
С	2.0		
E	1.35		

Note:

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.





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